

SN54ABT16373A, SN74ABT16373A 16-BIT TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS

SCBS160C – DECEMBER 1992 – REVISED MAY 1997

- Members of the Texas Instruments *Widebus*™ Family
- State-of-the-Art *EPIC-II B*™ BiCMOS Design Significantly Reduces Power Dissipation
- Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17
- Typical V_{OLP} (Output Ground Bounce) < 0.8 V at $V_{CC} = 5$ V, $T_A = 25^\circ\text{C}$
- High-Impedance State During Power Up and Power Down
- Distributed V_{CC} and GND Pin Configuration Minimizes High-Speed Switching Noise
- Flow-Through Architecture Optimizes PCB Layout
- High-Drive Outputs (-32 -mA I_{OH} , 64 -mA I_{OL})
- Package Options Include Plastic 300-mil Shrink Small-Outline (DL) and Thin Shrink Small-Outline (DGG) Packages and 380-mil Fine-Pitch Ceramic Flat (WD) Package Using 25-mil Center-to-Center Spacings

description

The 'ABT16373A are 16-bit transparent D-type latches with 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

These devices can be used as two 8-bit latches or one 16-bit latch. When the latch-enable (LE) input is high, the Q outputs follow the data (D) inputs. When LE is taken low, the Q outputs are latched at the levels set up at the D inputs.

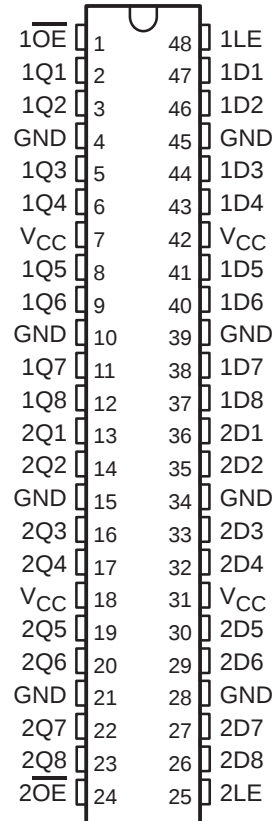
A buffered output-enable ($\overline{OE}$) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without need for interface or pullup components.

$\overline{OE}$ does not affect internal operations of the latch. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

When V_{CC} is between 0 and 2.1 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 2.1 V, $\overline{OE}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54ABT16373A is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74ABT16373A is characterized for operation from -40°C to 85°C .

SN54ABT16373A . . . WD PACKAGE
SN74ABT16373A . . . DGG OR DL PACKAGE
(TOP VIEW)



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PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.

**TEXAS
INSTRUMENTS**

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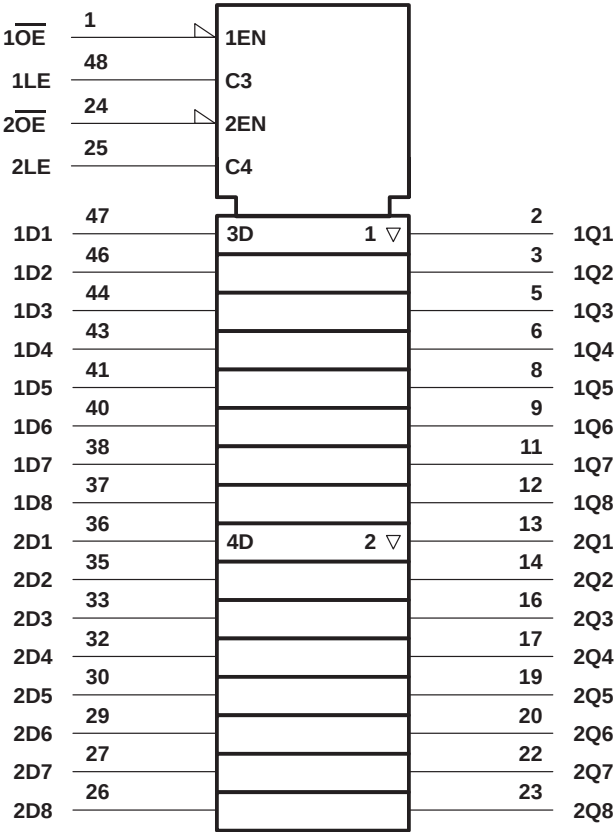
SN54ABT16373A, SN74ABT16373A
16-BIT TRANSPARENT D-TYPE LATCHES
WITH 3-STATE OUTPUTS

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FUNCTION TABLE
(each 8-bit section)

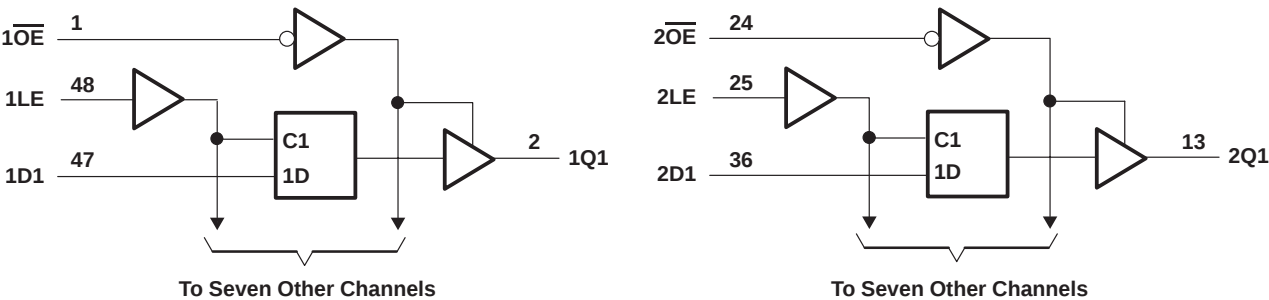
INPUTS			OUTPUT Q
$\overline{OE}$	LE	D	
L	H	H	H
L	H	L	L
L	L	X	Q_0
H	X	X	Z

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



SN54ABT16373A, SN74ABT16373A 16-BIT TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)[†]

Supply voltage range, V_{CC}	–0.5 V to 7 V
Input voltage range, V_I (see Note 1)	–0.5 V to 7 V
Voltage range applied to any output in the high or power-off state, V_O	–0.5 V to 5.5 V
Current into any output in the low state, I_O : SN54ABT16373A	96 mA
SN74ABT16373A	128 mA
Input clamp current, I_{IK} ($V_I < 0$)	–18 mA
Output clamp current, I_{OK} ($V_O < 0$)	–50 mA
Package thermal impedance, θ_{JA} (see Note 2): DGG package	89°C/W
DL package	94°C/W
Storage temperature range, T_{stg}	–65°C to 150°C

[†] Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
2. The package thermal impedance is calculated in accordance with EIA/JEDEC Std JESD51.

recommended operating conditions (see Note 3)

		SN54ABT16373A		SN74ABT16373A		UNIT
		MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage	4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage	2		2		V
V_{IL}	Low-level input voltage		0.8		0.8	V
V_I	Input voltage	0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current		–24		–32	mA
I_{OL}	Low-level output current		48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled			10	ns/V
$\Delta t/\Delta V_{CC}$	Power-up ramp rate	200		200		μs/V
T_A	Operating free-air temperature	–55	125	–40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.



SN54ABT16373A, SN74ABT16373A

16-BIT TRANSPARENT D-TYPE LATCHES

WITH 3-STATE OUTPUTS

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T _A = 25°C			SN54ABT16373A		SN74ABT16373A		UNIT
		MIN	TYP†	MAX	MIN	MAX	MIN	MAX	
V _{IK}	V _{CC} = 4.5 V, I _I = –18 mA			–1.2		–1.2		–1.2	V
V _{OH}	V _{CC} = 4.5 V, I _{OH} = –3 mA	2.5			2.5		2.5		V
	V _{CC} = 5 V, I _{OH} = –3 mA	3			3		3		
	V _{CC} = 4.5 V	I _{OH} = –24 mA	2		2				
		I _{OH} = –32 mA	2*				2		
V _{OL}	V _{CC} = 4.5 V	I _{OL} = 48 mA		0.55	0.55				V
		I _{OL} = 64 mA		0.55*			0.55		
V _{hys}			100						mV
I _I	V _{CC} = 0 to 5.5 V, V _I = V _{CC} or GND			±1		±1		±1	μA
I _{OZPU} ‡	V _{CC} = 0 to 2.1 V, V _O = 0.5 V to 2.7 V, $\overline{OE} = X$			±50		±50		±50	μA
I _{OZPD} ‡	V _{CC} = 2.1 V to 0, V _O = 0.5 V to 2.7 V, $\overline{OE} = X$			±50		±50		±50	μA
I _{OZH}	V _{CC} = 2.1 V to 5.5 V, V _O = 2.7 V, $\overline{OE} \geq 2$ V			10		10		10	μA
I _{OZL}	V _{CC} = 2.1 V to 5.5 V, V _O = 0.5 V, $\overline{OE} \geq 2$ V			–10		–10		–10	μA
I _{off}	V _{CC} = 0, V _I or V _O ≤ 4.5 V			±100				±100	μA
I _{CEX}	Outputs high	V _{CC} = 5.5 V, V _O = 5.5 V		50		50		50	μA
I _O §	V _{CC} = 5.5 V, V _O = 2.5 V	–50	–100	–180	–50	–180	–50	–180	mA
I _{CC}	Outputs high			2		2		2	mA
	Outputs low			85		85		85	
	Outputs disabled			2		2		2	
ΔI _{CC} ¶	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND			1.5		1.5		1.5	mA
C _i	V _I = 2.5 V or 0.5 V			3.5					pF
C _O	V _O = 2.5 V or 0.5 V			9.5					pF

* On products compliant to MIL-PRF-38535, this parameter does not apply.

† All typical values are at V_{CC} = 5 V.

‡ This parameter is characterized, but not production tested.

§ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

¶ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

		V _{CC} = 5 V, T _A = 25°C#		SN54ABT16373A		SN74ABT16373A		UNIT
		MIN	MAX	MIN	MAX	MIN	MAX	
t _w	Pulse duration, LE high	3.3		3.3		3.3		ns
t _{su}	Setup time, data before LE↓	1.5		2.4		1.5		ns
t _h	Hold time, data after LE↓	1		2.2		1		ns

These values apply only to the SN74ABT16373A.



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SN54ABT16373A, SN74ABT16373A
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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN54ABT16373A					UNIT
			V _{CC} = 5 V, T _A = 25°C			MIN	MAX	
			MIN	TYP	MAX			
t _{PLH}	D	Q	1.4	3.7	5.3	1.4	6.5	ns
t _{PHL}			2	4	5.4	2	6.5	
t _{PLH}	LE	Q	1.7	4.1	5.7	1.7	7	ns
t _{PHL}			2.3	4.3	5.6	2.3	6.3	
t _{PZH}	$\overline{OE}$	Q	1.1	3.4	5	1.1	6.4	ns
t _{PZL}			1.5	3.5	4.9	1.5	5.8	
t _{PHZ}	$\overline{OE}$	Q	2.4	5.1	7.1	2.4	8.3	ns
t _{PLZ}			1.6	4.4	6.3	1.6	8	

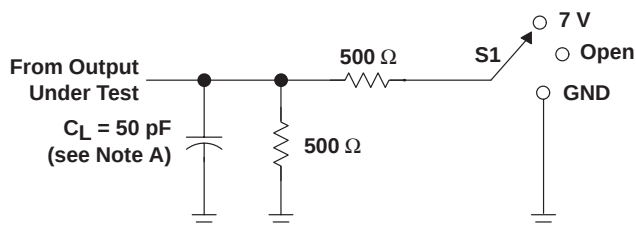
switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	SN74ABT16373A					UNIT
			V _{CC} = 5 V, T _A = 25°C			MIN	MAX	
			MIN	TYP	MAX			
t _{PLH}	D	Q	1.4	3.7	5.3	1.4	6.3	ns
t _{PHL}			2	4	5.4	2	6.2	
t _{PLH}	LE	Q	1.7	4.1	5.7	1.7	6.7	ns
t _{PHL}			2.3	4.3	5.6	2.3	6.1	
t _{PZH}	$\overline{OE}$	Q	1.1	3.4	5	1.1	6.1	ns
t _{PZL}			1.5	3.5	4.9	1.5	5.6	
t _{PHZ}	$\overline{OE}$	Q	2.4	5.1	7.1	2.4	8.1	ns
t _{PLZ}			1.6	4.4	5.8	1.6	6.5	

SN54ABT16373A, SN74ABT16373A 16-BIT TRANSPARENT D-TYPE LATCHES WITH 3-STATE OUTPUTS

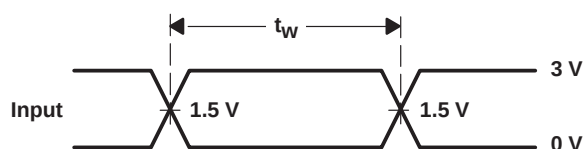
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PARAMETER MEASUREMENT INFORMATION

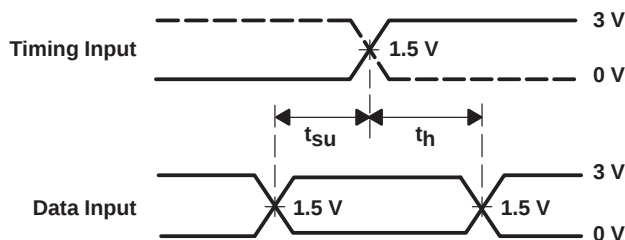


LOAD CIRCUIT

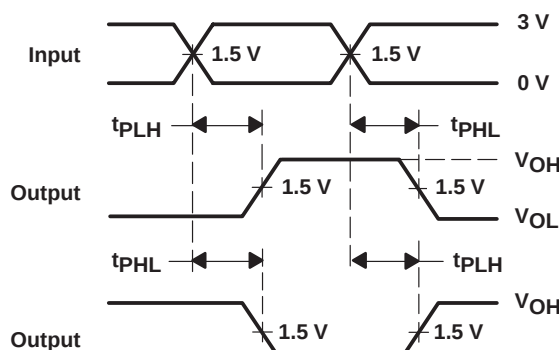
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	7 V
t_{PHZ}/t_{PZH}	Open



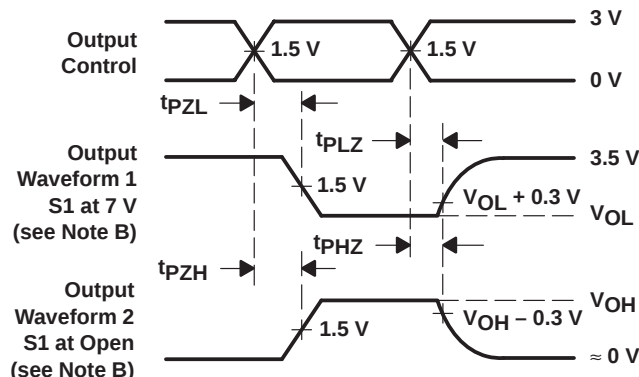
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

- NOTES: A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2.5 \text{ ns}$, $t_f \leq 2.5 \text{ ns}$.
D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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SN54ABT16373A, 16-Bit Transparent D-type Latches With 3-State Outputs
DEVICE STATUS: ACTIVE

PARAMETER NAME	SN54ABT16373A	SN74ABT16373A
Voltage Nodes (V)	5	5
Vcc range (V)	4.5 to 5.5	4.5 to 5.5
Input Level	TTL	TTL
Output Level	TTL	TTL
Output Drive (mA)		-32/64
No. of Outputs	16	16
Static Current		43.5
th (ns)		1
tpd max (ns)		6.7
tsu (ns)		1.5
Logic	True	True

FEATURES

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- Members of the Texas Instruments **Widebus™** Family
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DESCRIPTION

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Product Folder: SN54ABT16373A, 16-Bit Transparent D-type Latches With 3-State Outputs

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TECHNICAL DOCUMENTS

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DATASHEET

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Full datasheet in Acrobat PDF: [sn54abt16373a.pdf](#) (108 KB,Rev.C) (Updated: 05/01/1997)

APPLICATION NOTES

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- [Advanced BiCMOS Technology \(ABT\) Logic Characterization Information \(Rev. B\)](#) (SCBA008B - Updated: 06/01/1997)
- [Advanced BiCMOS Technology \(ABT\) Logic Enables Optimal System Design \(Rev. A\)](#) (SCBA001A - Updated: 03/01/1997)
- [Bus-Interface Devices With Output-Damping Resistors Or Reduced-Drive Outputs \(Rev. A\)](#) (SCBA012A - Updated: 08/01/1997)
- [Designing With Logic \(Rev. C\)](#) (SDYA009C - Updated: 06/01/1997)
- [Evaluation of Nickel/Palladium/Gold-Finished Surface-Mount Integrated Circuits](#) (SZZA026 - Updated: 06/20/2001)
- [Family of Curves Demonstrating Output Skews for Advanced BiCMOS Devices \(Rev. A\)](#) (SCBA006A - Updated: 12/01/1996)
- [Implications of Slow or Floating CMOS Inputs \(Rev. C\)](#) (SCBA004C - Updated: 02/01/1998)
- [Input and Output Characteristics of Digital Integrated Circuits](#) (SDYA010 - Updated: 10/01/1996)
- [Live Insertion](#) (SDYA012 - Updated: 10/01/1996)
- [Power-Up 3-State \(PU3S\) Circuits in TI Standard Logic Devices](#) (SZZA033 - Updated: 05/10/2002)
- [Quad Flatpack No-Lead Logic Packages \(Rev. C\)](#) (SCBA017C - Updated: 11/22/2002)
- [TI IBIS File Creation, Validation, and Distribution Processes](#) (SZZA034 - Updated: 08/29/2002)
- [Understanding Advanced Bus-Interface Products Design Guide](#) (SCAA029, 253 KB - Updated: 05/01/1996)
- [Understanding and Interpreting Texas Instruments Standard-Logic Products Data Sh \(Rev. A\)](#) (SZZA036A - Updated: 02/27/2003)

MORE LITERATURE

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- [Enhanced Plastic Portfolio Brochure](#) (SGZB004, 387 KB - Updated: 08/19/2002)
- [Logic Reference Guide](#) (SCYB004, 1032 KB - Updated: 10/23/2001)
- [MicroStar Junior BGA Design Summary](#) (SCET004, 167 KB - Updated: 07/28/2000)
- [Military Brief](#) (SGYN138, 803 KB - Updated: 10/10/2000)
- [Overview of IEEE Std 91-1984, Explanation of Logic Symbols Training Booklet \(Rev. A\)](#) (SDYZ001A, 138 KB - Updated: 07/01/1996)
- [Palladium Lead Finish User's Manual](#) (SDYV001, 2041 KB - Updated: 11/01/1996)
- [QML Class V Space Products Military Brief \(Rev. A\)](#) (SGZN001A, 257 KB - Updated: 10/07/2002)

USER GUIDES

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- [LOGIC Pocket Data Book](#) (SCYD013, 4837 KB - Updated: 12/05/2002)

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PRICING/AVAILABILITY/PKG

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ORDERABLE DEVICE	STATUS	PACKAGE TYPE PINS		TEMP (°C)	DSCC NUMBER	PRODUCT CONTENT	BUDGETARY PRICING QTY \$US	STD PACK QTY	IN STOCK	IN PROGRESS QTY DATE	LEAD TIME	DISTRIBUTOR COMPANY REGION		IN STOCK	PURCHASE
5962-9320001QXA	ACTIVE	CFP (WD)	48	-55 TO 125		View Contents	1KU 18.96	1	248 *	> 10k 20 May	8 WKS	None Reported View Distributors			
SNJ54ABT16373AWD	ACTIVE	CFP (WD)	48	-55 TO 125	5962-9320001QXA	View Contents	1KU 18.96	1	1098 *	> 10k 20 May	8 WKS	Avnet Americas		2	BUY NOW

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